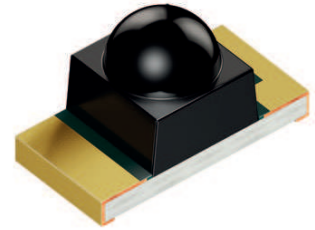


# High Power Infrared Emitter (850 nm) Version 1.5

## SFH 4059



### Features:

- High optical power
- Very small package: (LxWxH) 3.2 mm x 1.6 mm x 1.85 mm
- UL version available ( ordering code & test conditions on request)

### Applications

- Miniature photointerrupters
- Industrial electronics
- For control and drive circuits
- Mobile devices

### Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

### Ordering Information

Type:	Irradiance $E_e$ [mW/cm <sup>2</sup> ] $I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$	Radiant intensity $I_{e, \text{typ}}$ [mW/sr] $I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$	Ordering Code
SFH 4059-QS	15 ( $\geq 6.3$ )	100	Q65111A2991
SFH 4059-RS	10 ... 32		Q65111A7272

Note:  $I_e$  measured with a detector (11.3 mm diameter) in 100 mm distance ( $\Omega = 0.01 \text{ sr}$ ) to the device surface

$E_e$  measured in the near field with a detector (7.2 mm diameter) in 20 mm distance ( $\Omega = 0.1 \text{ sr}$ ) to the device surface

**Maximum Ratings** ( $T_A = 25\text{ °C}$ )

Parameter	Symbol	Values	Unit
Operation and storage temperature range	$T_{op}; T_{stg}$	-40 ... 85	°C
Reverse voltage	$V_R$	5	V
Forward current	$I_F$	70	mA
Surge current ( $t_p \leq 300\ \mu\text{s}$ , $D = 0$ )	$I_{FSM}$	0.7	A
Power consumption	$P_{tot}$	140	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	$V_{ESD}$	2	kV
Thermal resistance junction - ambient <sup>1) page 13</sup>	$R_{thJA}$	540	K / W
Thermal resistance junction - soldering point <sup>2) page 13</sup>	$R_{thJS}$	360	K / W

**Characteristics** ( $T_A = 25\text{ °C}$ )

Parameter	Symbol	Values	Unit
Peak wavelength ( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )	$\lambda_{peak}$	860	nm
Centroid wavelength ( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )	$\lambda_{centroid}$	850	nm
Spectral bandwidth at 50% of $I_{max}$ ( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )	$\Delta\lambda$	30	nm
Half angle	$\varphi$	$\pm 10$	°
Dimensions of active chip area	L x W	0.2 x 0.2	mm x mm
Rise and fall time of $I_e$ ( 10% and 90% of $I_{e\ max}$ ) ( $I_F = 70\text{ mA}$ , $R_L = 50\ \Omega$ )	$t_r, t_f$	12	ns
Forward voltage ( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )	$V_F$	1.6 ( $\leq 2$ )	V
Forward voltage ( $I_F = 500\text{ mA}$ , $t_p = 100\ \mu\text{s}$ )	$V_F$	2.4	V
Reverse current ( $V_R = 5\text{ V}$ )	$I_R$	not designed for reverse operation	$\mu\text{A}$
Total radiant flux ( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )	$\Phi_e$	40	mW
Radiant intensity ( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )	$I_{e, typ}$	100	mW/sr

Parameter		Symbol	Values	Unit
Temperature coefficient of $I_e$ or $\Phi_e$ ( $I_F = 70$ mA, $t_p = 20$ ms)	(typ)	$TC_I$	-0.5	% / K
Temperature coefficient of $V_F$ ( $I_F = 70$ mA, $t_p = 20$ ms)	(typ)	$TC_V$	-0.7	mV / K
Temperature coefficient of wavelength ( $I_F = 70$ mA, $t_p = 20$ ms)	(typ)	$TC_\lambda$	0.3	nm / K

### Grouping ( $T_A = 25$ °C)

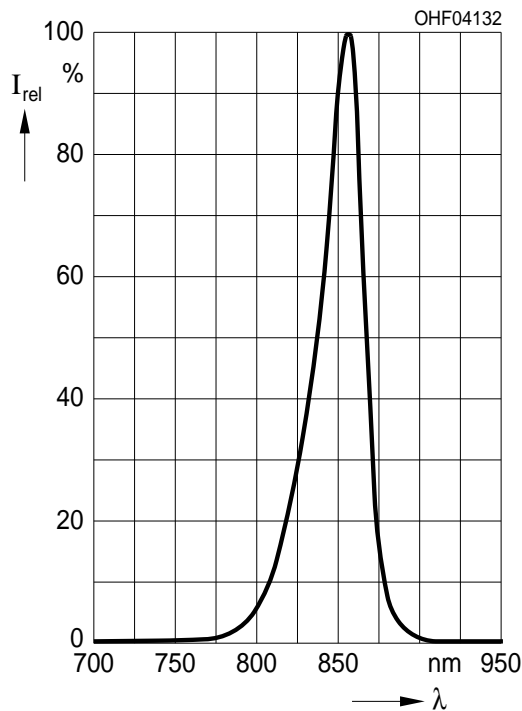
Parameter	Min Irradiance	Max Irradiance
	$I_F = 70$ mA, $t_p = 20$ ms $E_{e, \min}$ [mW/cm <sup>2</sup> ]	$I_F = 70$ mA, $t_p = 20$ ms $E_{e, \max}$ [mW/cm <sup>2</sup> ]
SFH 4059 -Q	6.3	12.5
SFH 4059 -R	10	20
SFH 4059 -S	16	32

Note:  $E_e$  measured in the near field with a detector (7.2 mm diameter) in 20 mm distance ( $\Omega = 0.1$  sr) to the device surface

Only one group in one packing unit (variation lower 2:1).

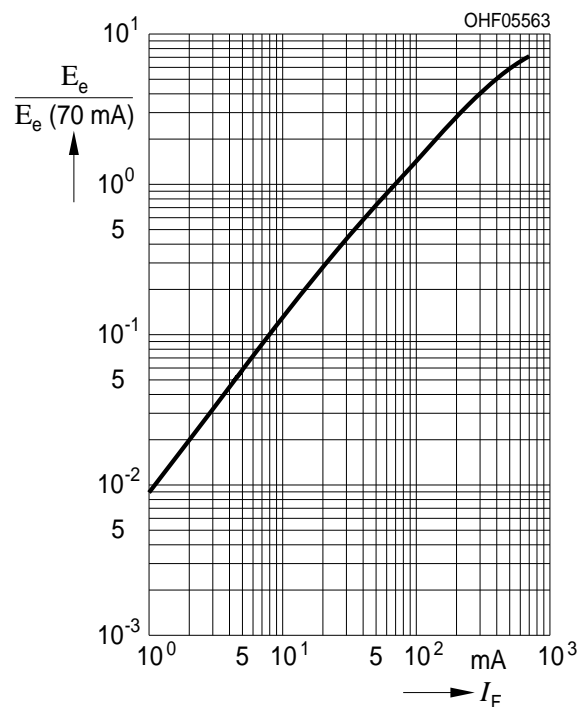
### Relative Spectral Emission <sup>3) page 13</sup>

(typ)  $I_{rel} = f(\lambda)$ ,  $T_A = 25$  °C



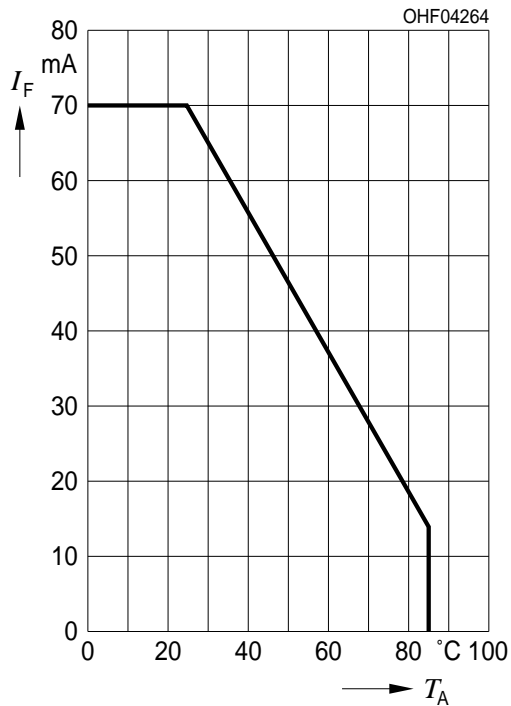
### Irradiance <sup>3) page 13</sup>

$E_e/E_e(70\text{mA}) = f(I_F)$ , Single pulse,  $t_p = 25$   $\mu$ s,  $T_A = 25$  °C



**Max. Permissible Forward Current**

$I_F = f(T_A), R_{thJA} = 540K/W$



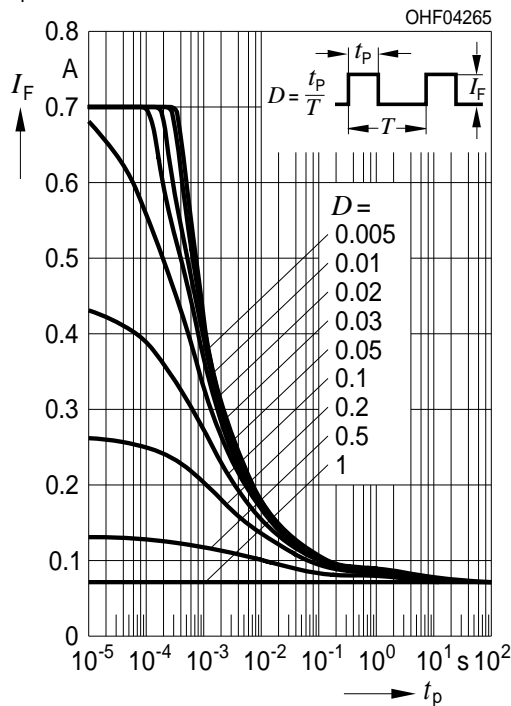
**Forward Current** <sup>3) page 13</sup>

$I_F = f(V_F), \text{ single pulse, } t_p = 100 \mu s, T_A = 25^\circ C$



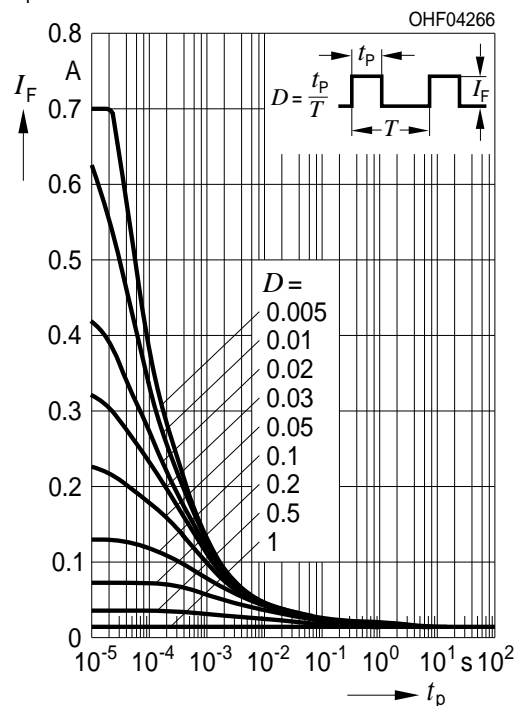
**Permissible Pulse Handling Capability**

$I_F = f(t_p), T_A = 25^\circ C, \text{ duty cycle } D = \text{parameter}$



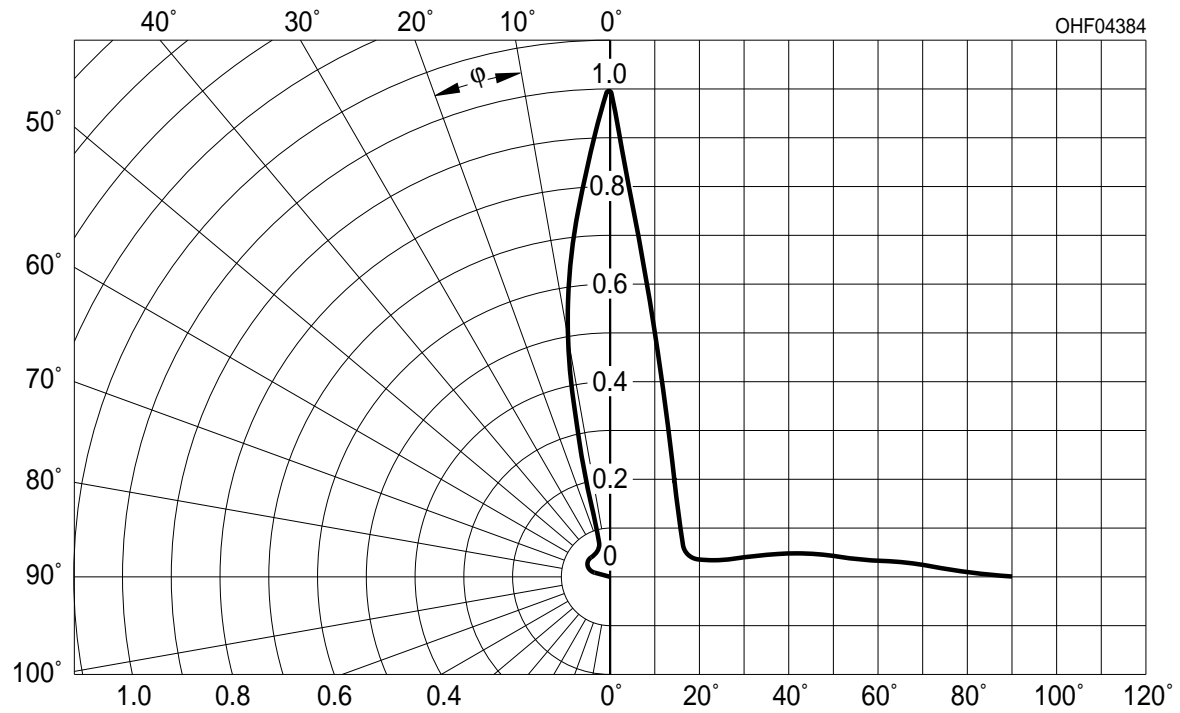
**Permissible Pulse Handling Capability**

$I_F = f(t_p), T_A = 85^\circ C, \text{ duty cycle } D = \text{parameter}$

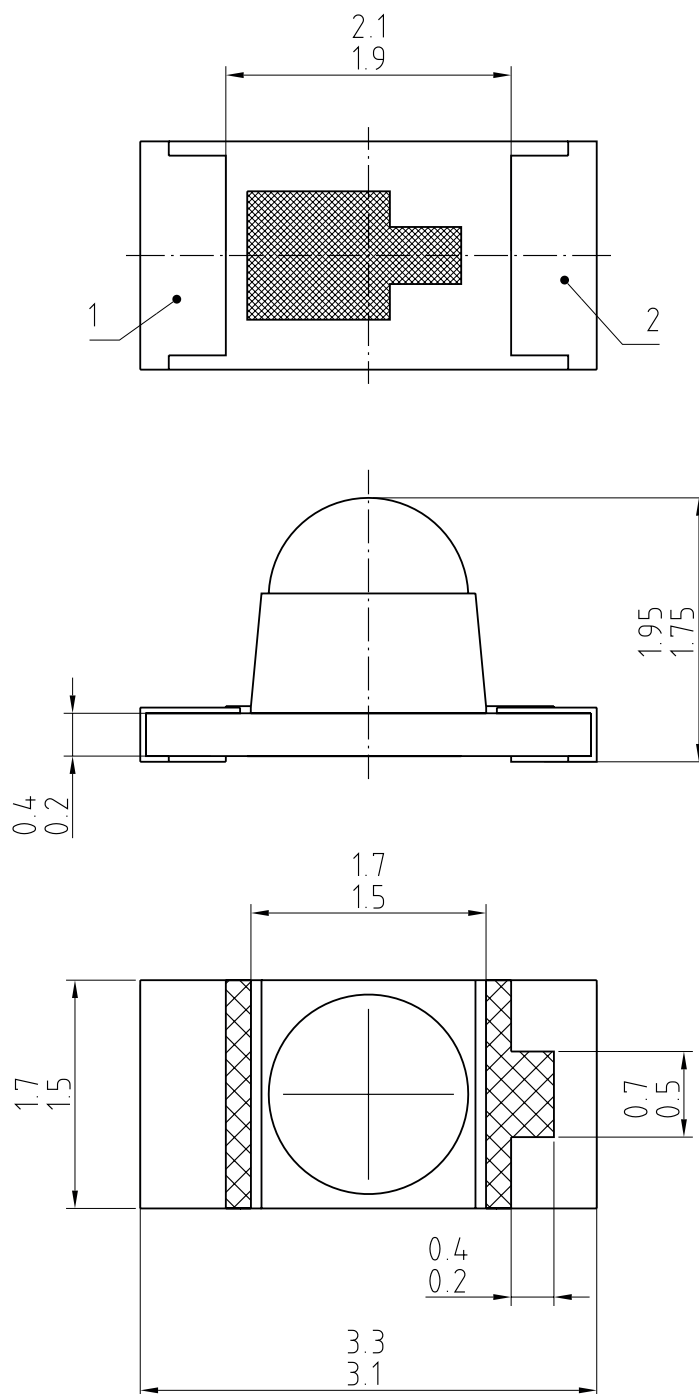


**Radiation Characteristics** <sup>3) page 13</sup>

$$I_{\text{rel}} = f(\phi), T_A = 25^\circ\text{C}$$



## Package Outline



Dimensions in mm.

C63062-A4074-A1...-05

**Pinning**

Pin	Description
1	cathode
2	anode

**Package**

Chiplid

**Approximate Weight:**

5.4 mg

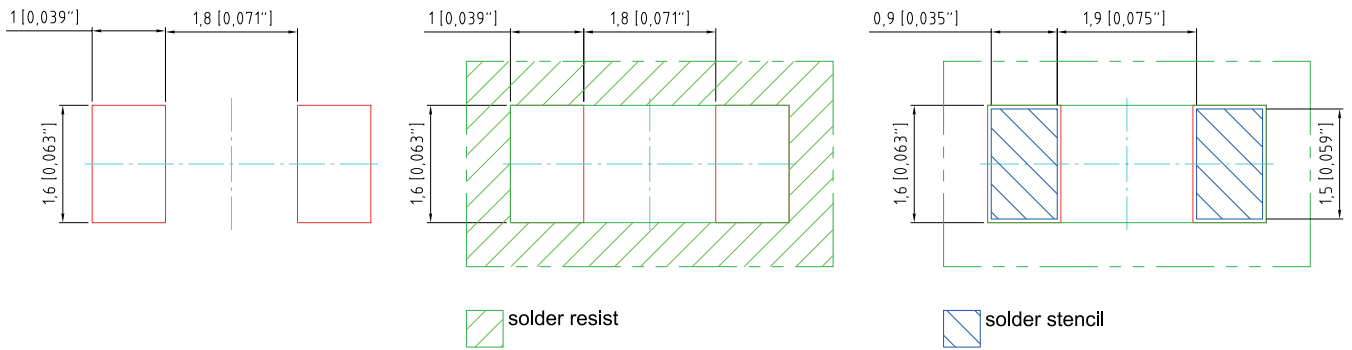
**Note:**

Package: Epoxy

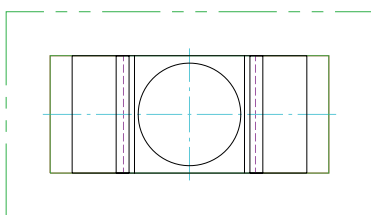
**Note:**

Colour: black

**Recommended Solder Pad**



Component Location on Pad

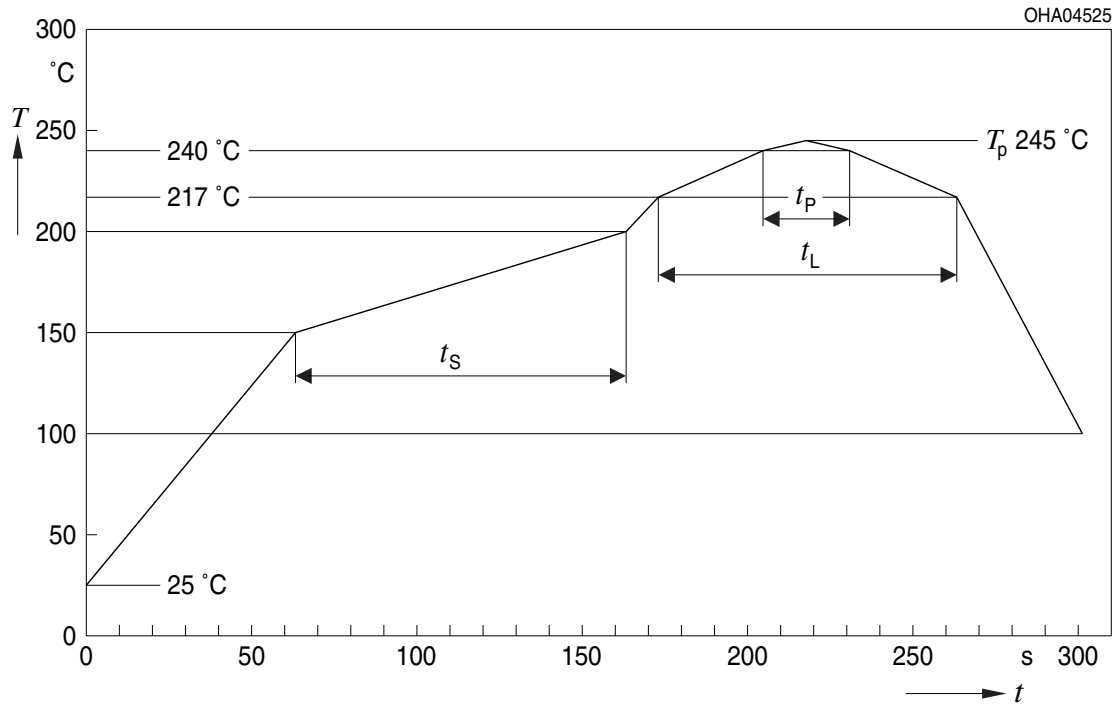


*Dimensions in mm (inch).*

E062.3010.78-04

## Reflow Soldering Profile

Product complies to MSL Level 3 acc. to JEDEC J-STD-020D.01



OHA04612

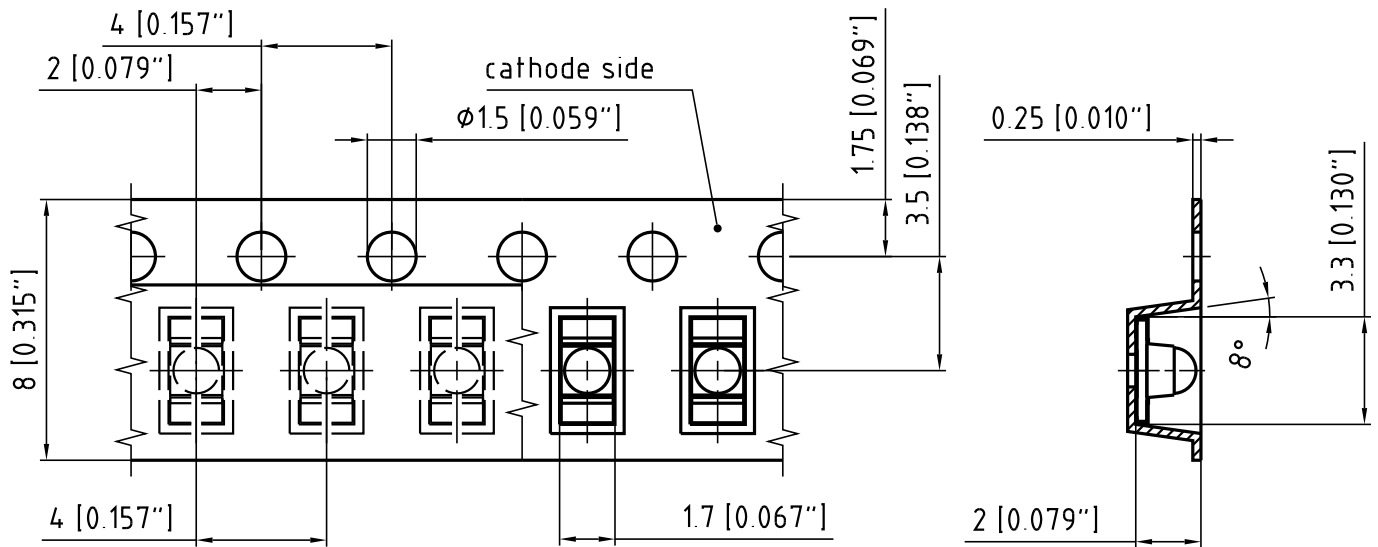
Profile Feature Profil-Charakteristik	Symbol Symbol	Pb-Free (SnAgCu) Assembly			Unit Einheit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time $t_S$ $T_{Smin}$ to $T_{Smax}$	$t_S$	60	100	120	s
Ramp-up rate to peak*) $T_{Smax}$ to $T_P$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_L$		80	100	s
Peak temperature	$T_P$		245	260	°C
Time within 5 °C of the specified peak temperature $T_P - 5$ K	$t_P$	10	20	30	s
Ramp-down rate* $T_P$ to 100 °C			3	6	K/s
Time 25 °C to $T_P$				480	s

All temperatures refer to the center of the package, measured on the top of the component

\* slope calculation  $DT/Dt$ :  $Dt$  max. 5 s; fulfillment for the whole T-range



**Taping**

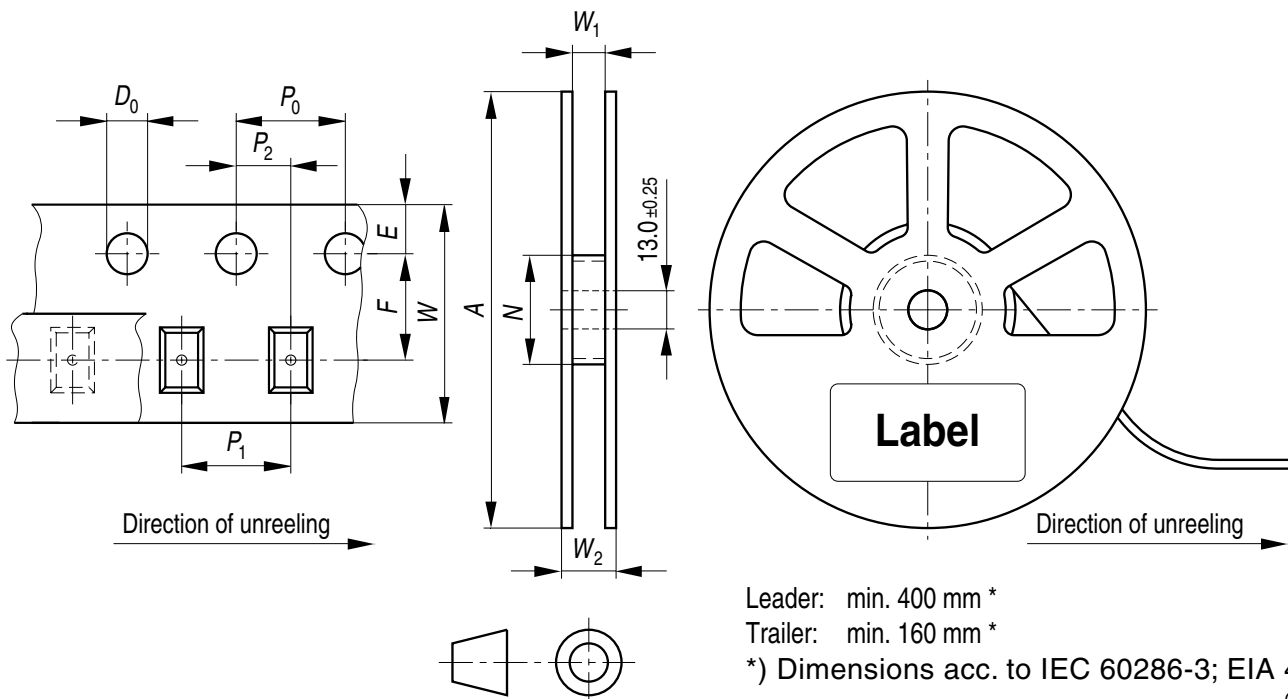


C63062-A4074-B1-01

*Dimensions in mm (inch).*

**Tape and Reel**

8 mm tape with 2000 pcs. on  $\phi$  180 mm reel



Leader: min. 400 mm \*

Trailer: min. 160 mm \*

\*) Dimensions acc. to IEC 60286-3; EIA 481-D

OHAY0324

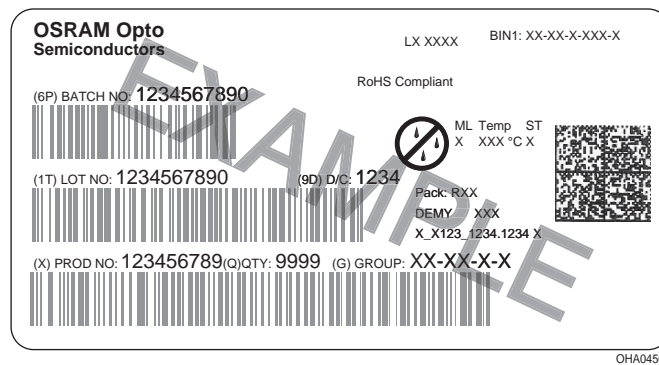
## Tape dimensions [mm]

W	P <sub>0</sub>	P <sub>1</sub>	P <sub>2</sub>	D <sub>0</sub>	E	F
8 + 0.3 / -0.1	4 ± 0.1	2 ± 0.05 or 4 ± 0.1	2 ± 0.05	1.5 ± 0.1	1.75 ± 0.1	3.5 ± 0.05

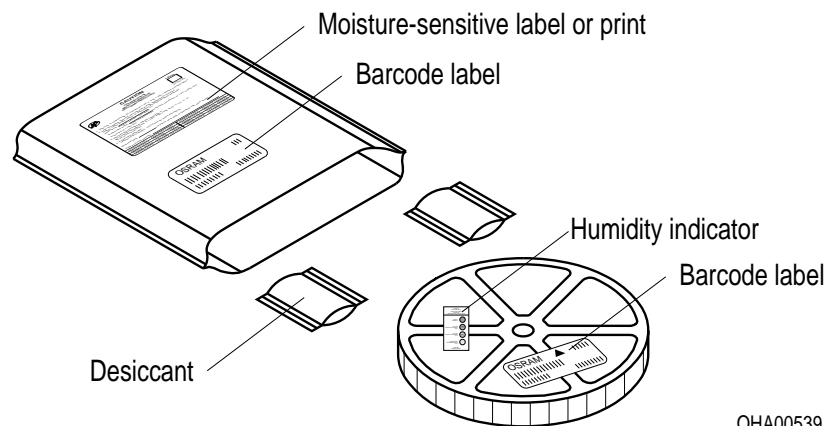
## Reel dimensions [mm]

A	W	N <sub>min</sub>	W <sub>1</sub>	W <sub>2max</sub>
180	8	60	8.4 + 2	14.4

## Barcode-Product-Label (BPL)



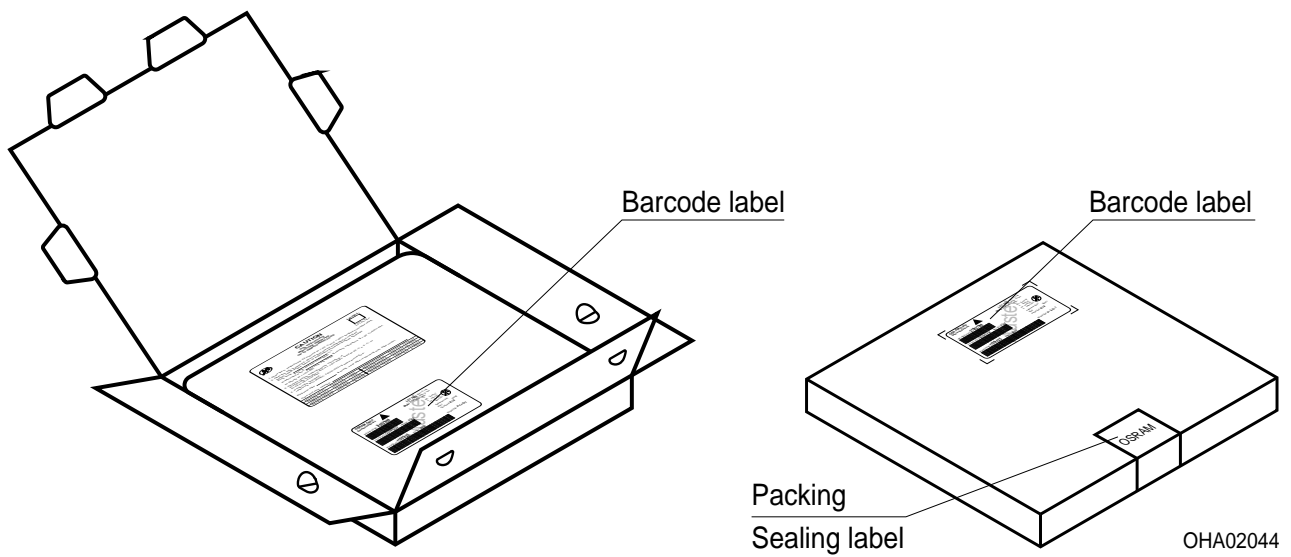
## Dry Packing Process and Materials



## Note:

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative references like JEDEC.

## Transportation Packing and Materials



## Dimensions of transportation box in mm

Width	Length	Height
200 ± 5	195 ± 5	30 ± 5

**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

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\*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

**Glossary**

- 1) **Thermal resistance:** junction -ambient, mounted on PC-board (FR4), pads size 5 mm<sup>2</sup> each
- 2) **Thermal resistance:** junction - soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- 3) **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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EU RoHS and China RoHS compliant product



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按照中国的相关法规和标准，不含有毒有害物质或元素。

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